

Polar ™ HiPerFET™ **Power MOSFET**

IXFA7N100P IXFP7N100P IXFH7N100P

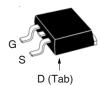
N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Rectifier



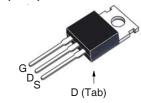
G -	

$V_{\scriptscriptstyle DSS}$	=	1000V
I _{D25}	=	7A
R _{DS(on)}	≤	1.9Ω

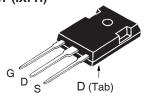
TO-263 (IXFA)



TO-220 (IXFP)



TO-247 (IXFH)



G = Gate	D	=	Drain
S = Source	Tab	=	Drain

Features

- International Standard Packages
- Fast Intrinsic Rectifier
- Avalanche Rated
- Low R_{DS(ON)} and Q_G
 Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- · Robotics and Servo Controls

Symbol	Test Conditions	Maximum	Ratings
V _{DSS}	$T_J = 25$ °C to 150°C	1000	V
V _{DGR}	$T_{_{ m J}}$ = 25°C to 150°C, $R_{_{ m GS}}$ = 1M Ω	1000	V
V _{GSS}	Continuous	±30	V
V _{GSM}	Transient	<u>±</u> 40	V
I _{D25}	T _C = 25°C	7	A
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	18	Α
I _A	T _C = 25°C	7	Α
E _{as}	$T_{c} = 25^{\circ}C$	300	mJ
dv/dt	$I_{_{S}} \le I_{_{DM}}, V_{_{DD}} \le V_{_{DSS}}, T_{_{J}} \le 150^{\circ}C$	10	V/ns
P _D	T _C = 25°C	300	W
T _J		-55 +150	°C
T _{JM}		150	°C
T _{stg}		-55 +150	°C
T _L T _{SOLD}	Maximum Lead Temperature for Solderi Plastic Body for 10s	ng 300 260	°C °C
F _c	Mounting Force (TO-263) Mounting Torque (TO-220 & TO-247)	1065 / 2.214.6 1.13 / 10	N/lb Nm/lb.in
Weight	TO-263 TO-220 TO-247	2.5 3.0 6.0	g 9

SymbolTest ConditionsChara $(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		cteristic ' Typ.	Values Max		
BV _{DSS}	$V_{GS} = 0V, I_{D} = 250\mu A$	1000			V
$V_{\rm GS(th)}$	$V_{DS} = V_{GS}$, $I_{D} = 1 \text{mA}$	3.0		6.0	V
I _{GSS}	$V_{gS} = \pm 30V, V_{DS} = 0V$			±100	nA
DSS	$V_{DS} = V_{DSS}$, $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$				μA mA
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$			1.9	Ω



SymbolTest ConditionsChara $(T_J = 25^{\circ}\text{C}, \text{Unless Otherwise Specified})$ Min.		Chara	acteristic Values		
		Min.	Тур.	Max	
g _{fs}		$V_{DS} = 20V, I_{D} = 0.5 \cdot I_{D25}, Note 1$	3.6	6.0	S
R_{Gi}		Gate Input Resistance		1.8	Ω
C _{iss})			2590	pF
C _{oss}	}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		158	pF
\mathbf{C}_{rss}	J			26	pF
t _{d(on)})	Deciative Cuitabing Times		25	ns
t,		Resistive Switching Times		49	ns
$\mathbf{t}_{d(off)}$		$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		42	ns
t _f	J	$R_{\rm g} = 10\Omega \text{ (External)}$		44	ns
$\mathbf{Q}_{g(on)}$)			47	nC
\mathbf{Q}_{gs}	}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		21	nC
\mathbf{Q}_{gd}	J			21	nC
R _{thJC}					0.42 °C/W
$\mathbf{R}_{ ext{thCS}}$		TO-220		0.50	°C/W
		TO-247		0.21	°C/W

Source-Drain Diode

Symbol		Chara	cteristic		
$(T_J = 25^{\circ}C, L)$	Inless Otherwise Specified)	Min.	Тур.	Max	
I _s	V _{GS} = 0V, Note1			7	Α
SM	Repetitive, Pulse Width Limited by $\mathrm{T_{_{JM}}}$			28	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.3	V
$\left\{ egin{array}{c} \mathbf{t}_{rr} \\ \mathbf{Q}_{RM} \\ \mathbf{I}_{RM} \end{array} ight. ight.$	$I_{_{\rm F}} = 3.5 \text{A}, -\text{di/dt} = 100 \text{A/} \mu \text{s}$ $V_{_{\rm R}} = 100 \text{V}$		0.4 4.0	300	ns μC A

1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$. Note



Fig. 1. Output Characteristics @ T_J = 25°C

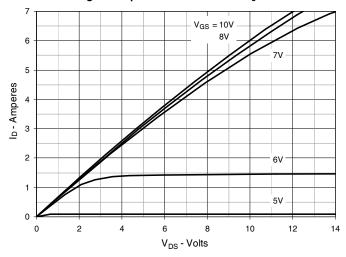


Fig. 2. Extended Output Characteristics @ T_J = 25°C

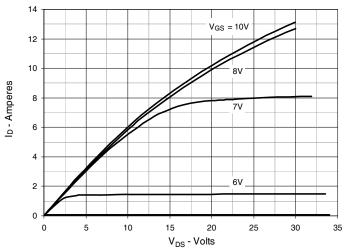


Fig. 3. Output Characteristics @ T_J = 125°C

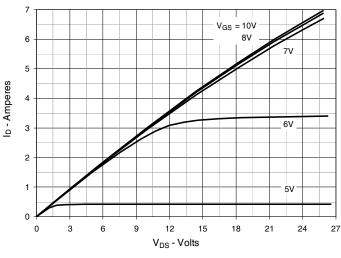


Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 3.5A$ Value vs. Junction Temperature

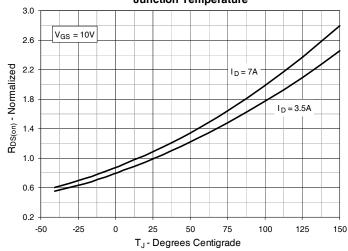


Fig. 5. $R_{DS(on)}$ Normalized to I_D = 3.5A Value vs.

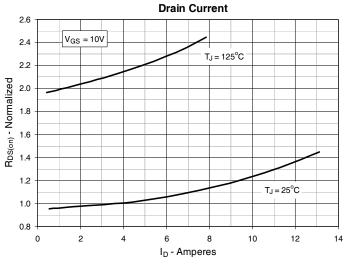
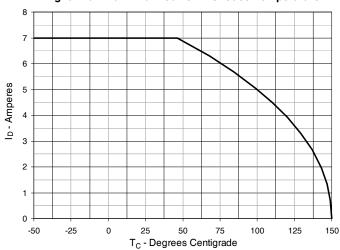
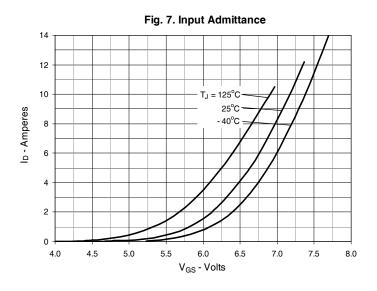
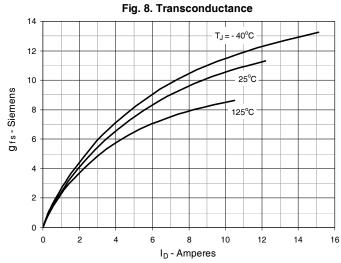


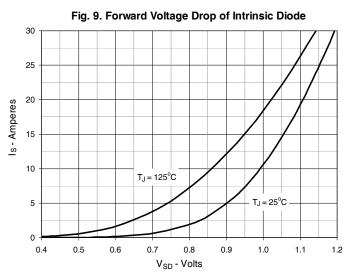
Fig. 6. Maximum Drain Current vs. Case Temperature

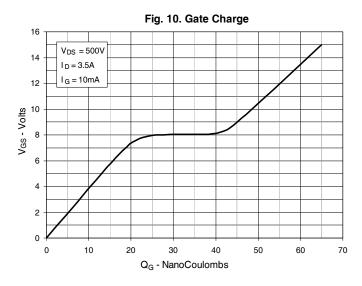


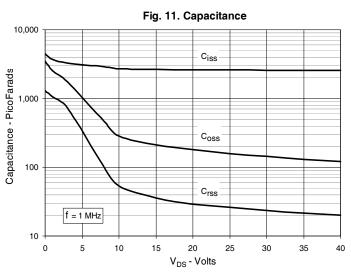


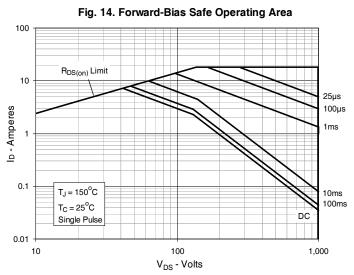












IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.



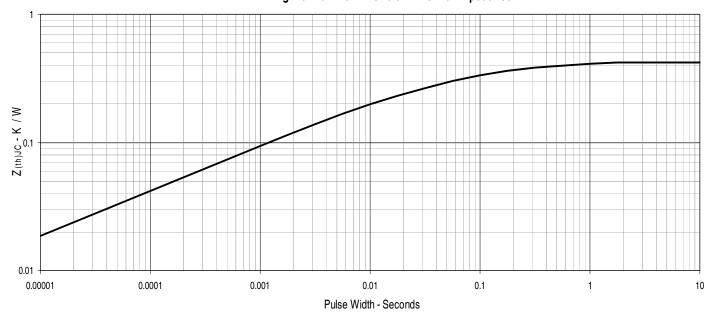
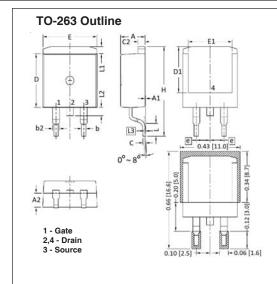
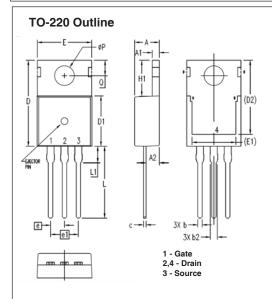


Fig. 13. Maximum Transient Thermal Impedance

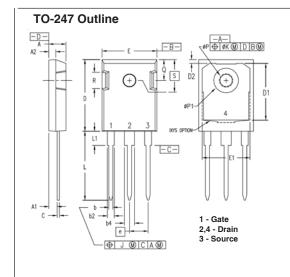




SYM	INCHES		MILLIMETER	
SIM	MIN	MAX	MIN	MAX
Α	.170	.185	4.30	4.70
A1	.000	.008	0.00	0.20
A2	.091	.098	2.30	2.50
Ь	.028	.035	0.70	0.90
b2	.046	.060	1.18	1.52
С	.018	.024	0.45	0.60
C2	.049	.060	1.25	1.52
D	.340	.370	8.63	9.40
D1	.300	.327	7.62	8.30
E	.380	.410	9.65	10.41
E1	.270	.330	6.86	8.38
е	.100	BSC	2.54	BSC
Н	.580	.620	14.73	15.75
L	.075	.105	1.91	2.67
L1	.039	.060	1.00	1.52
L2	_	.070	_	1.77
L3	.010	BSC	0.254	BSC



MYS	INCHES		MILLIMETERS	
2111	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.047	.055	1.20	1.40
A2	.079	.106	2.00	2.70
Ь	.024	.039	0.60	1.00
b2	.045	.057	1.15	1.45
O	.014	.026	0.35	0.65
О	.587	.626	14.90	15.90
D1	.335	.370	8.50	9.40
(D2)	.500	.531	12.70	13.50
Ε	.382	.406	9.70	10.30
(E1)	.283	.323	7.20	8.20
е	.100 BSC 2.54		BSC	
e1	.200	BSC	5.08 BSC	
H1	.244	.268	6.20	6.80
Г	.492	.547	12.50	13.90
L1	.110	.154	2.80	3.90
ØΡ	.134	.150	3.40	3.80
Q	.106	.126	2.70	3.20



SYM	INCHES		MILLIMETERS	
STIVI	MIN	MAX	MIN	MAX
Α	.190	.205	4.83	5.21
Α1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b2	.075	.087	1.91	2.20
b4	.115	.126	2.92	3.20
С	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.690	16.51	17.53
D2	.035	.050	0.89	1.27
Ε	.620	.635	15.75	16.13
E1	.545	.565	13.84	14.35
е	.215	BSC	5.45	BSC
J		.010		0.25
K		.025		0.64
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
ØΡ	.140	.144	3.55	3.65
øP1	.275	.290	6.99	7.37
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.242	BSC	6.15	BSC

